NSN 5961-01-009-0290

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-009-0290

Inclosure Material:

Glass and metal

Overall Length:

Between 0.250 inches and 0.340 inches

Overall Diameter:

0.620 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

700.0 collector to base voltage/static/emitter open and 700.0 collector to emitter voltage, dc with specified circuit between base and emitter

and 5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

3.00 amperes source cutoff current

Power Rating Per Characteristic:

40.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

13973-862117 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

1 case and 2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fiig:

A110a0